

Application Data Sheet

Inventor Information

Inventor One Given Name:	Yoshinao
Family Name:	MORIKAWA
Name Suffix:	
Postal Address Line One	607-38, Ichibucho,
Postal Address Line Two	
City:	Ikoma-shi
State or Province:	Nara
Postal or Zip Code:	
Citizenship Country:	Japan

Correspondence Information

Name Line One:	Madeline Johnston
Name Line Two:	Morrison & Foerster LLP
Address Line One:	755 Page Mill Rd.
Address Line Two:	
City:	Palo Alto
State or Province:	California
Postal or Zip Code:	94304-1018
Telephone:	650-813-5840
Fax:	650-494-0792
Electronic Mail:	mjohnston@mofo.com

Application Information

Title Line One:	REFERENCE VOLTAGE GENERATION THE
Title Line Two:	CIRCUIT FOR SEMICONDUCTOR MEMORY
Title Line Three:	DEVICE, MEMORY READING CIRCUIT
Title Line Four:	INCLUDING SAME, AND ELECTRONIC
Title Line Five:	INFORMATION DEVICE INCLUDING THE SAME
Total Drawing Sheets:	14
Formal Drawings?:	Yes
Application Type:	Utility
Docket Number:	299002054200

Representative Information

Representative Customer Number:	25226
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Continuity Information

This application is a:

> Application One:

Filing Date:

which is a:

>>Application Two:

Filing Date:

which is a:

>>>Application Three:

Filing Date:

Prior Foreign Applications

Foreign Application One:

2001-057499

Filing Date:

March 1, 2001

Country:

Japan

Priority Claimed:

Yes